Features

- Dual RF input for antenna space and frequency diversity, LNA cascading or differential feeding
- ☐ Fully integrated PLL-based synthesizer
- ☐ 2nd mixer with image rejection
- □ Reception of ASK or FSK modulated signals
- Wide operating voltage
- ☐ Very low standby current consumption
- ☐ Low operating current consumption
- ☐ Internal IF filter
- □ Internal FSK demodulator
- ☐ Average or peak detection data slicer mode
- ☐ RSSI output with high dynamic range for RF level indication
- Noise cancellation filter
- ☐ MCU clock output
- ☐ High over-all frequency accuracy
- 32-pin Quad Flat No-Lead Package (QFN)

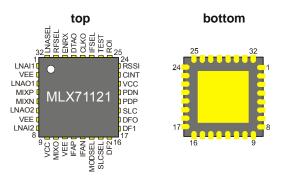
Ordering Information

Part Number	Temperature Code	Package Code	Delivery Form
MLX71121	C (-10 °C to 70 °C)	LQ (32 L QFN 5x5 Quad)	73 pc/tube 5000 pc/T&R

Application Examples

- General digital and analog RF receivers at 300 to 930MHz
- ☐ Automatic meter reading (AMR)
- ☐ Consumer remote controls
- □ Low power telemetry systems
- □ Alarm and security systems
- □ Garage and gate controls
- ☐ Home and building automation

Pin Description



General Description

The MLX71121 is a multi-band, single-channel RF receiver based on a double-conversion super-heterodyne architecture. It can receive FSK and ASK modulated signals. The IC is designed for general purpose applications for example in the European bands at 433MHz and 868MHz or for similar applications in North America or Asia, for example at 315MHz or 915MHz.



300 to 930MHz FSK/FM/ASK Receiver

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MLX71121 300 to 930MHz FSK/FM/ASK Receiver

1 Theory of Operation

1.1 General

The MLX71121 receiver architecture is based on a double-conversion super-heterodyne approach. The two LO signals are derived from an on-chip integer-N PLL frequency synthesizer. The PLL reference frequency is derived from a crystal (XTAL). As the first intermediate frequency (IF1) is very high, a reasonably high degree of image rejection is provided even without using an RF front-end filter. At applications asking for very high image rejections, cost-efficient RF front-end filtering can be realized by using a SAW filter in front of the LNA. The second mixer MIX2 is an image-reject mixer.

The receiver signal chain can be setup by one or two low noise amplifiers (LNA1, LNA2), two down-conversion mixers (MIX1, MIX2), an on-chip IF filter (IFF) as well as an IF amplifier (IFA). By choosing the required modulation via an FSK/ASK switch (at pin MODSEL), either the on-chip FSK demodulator (FSK DEMOD) or the RSSI-based ASK detector is selected. A second order data filter (OA1) and a data slicer (OA2) follow the demodulator. The data slicer threshold can be generated from the mean-value of the data stream or by means of the positive and negative peak detectors (PKDET+/-). Some post-processing of the data output signal can be performed by means a noise cancellation filter (NCF).

The dual LNA configuration can be used for antenna space diversity or antenna frequency diversity or to setup an LNA cascade (to further improve the input sensitivity). Another option is to set up the two LNAs for feeding the RF signal differentially.

A sequencer circuit (SEQ) controls the timing during start-up. This is to reduce start-up time and to minimize power dissipation.

A clock output, which is a divide-by-8 version of the crystal oscillator signal, can be used to drive a microcontroller. The clock output is an open drain and gets activated only if a loading resistor is connected to positive supply.

1.2 Technical Data Overview

Input frequency ranges: 300 to 470MHz	Image rejection:
610 to 930MHz	65dB 1 st IF (with external RF front-end filter)
Power supply range: 2.1 to 5.5V	25dB 2 nd IF (internal image rejection)
Temperature range: -10 to +70°C	Maximum data rate: 50kps RZ (bi-phase) code
Shutdown current: 50 nA	100kps NRZ
Operating current: 10.0 to 11.1mA	Spurious emission: < -54dBm
FSK input sensitivity: -107dBm* (433MHz)	Usable RSSI range: 45 to 55dB
ASK input sensitivity: -112dBm* (433MHz)	Crystal frequency: 16 to 27MHz
Internal IF: 1.8MHz with 300kHz 3dB bandwidth	MCU clock frequency: 2.0 to 3.4MHz
FSK deviation range: ±10kHz to ±100kHz	

^{*} at 4kbps NRZ, BER = 3·10⁻³, at LNA input pins

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1.3 Block Diagram

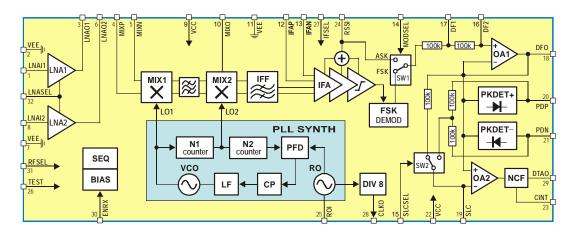


Fig. 1: MLX71121 block diagram

The MLX71121 receiver IC consists of the following building blocks:

- PLL synthesizer (PLL SYNTH) to generate the first and second local oscillator signals LO1 and LO2.
 The PLL SYNTH consists of a fully integrated voltage-controlled oscillator (VCO), a distributed feedback
 divider chain (N1,N2), a phase-frequency detector (PFD) a charge pump (CP), a loop filter (LF) and a
 crystal-based reference oscillator (RO).
- Two low-noise amplifiers (LNA1, LNA2) for high-sensitivity RF signal reception
- First mixer (MIX1) for down-conversion of the RF signal to the first IF (intermediate frequency)
- Second mixer (MIX2) with image rejection for down-conversion from the first to the second IF
- IF Filter (IFF) with a 1.8MHz center frequency and a 300kHz 3dB bandwidth
- IF amplifier (IFA) to provide a high voltage gain and an RSSI signal output
- FSK demodulator (FSK DEMOD)
- Operational amplifiers OA1 and OA2 for low-pass filtering and data slicing, respectively
- Positive (PKDET+) and negative (PKDET-) peak detectors
- Switches SW1 to select between FSK and ASK as well as SW2 to chose between averaging or peak detection mode.
- Noise cancellation filter (NCF)
- Sequencer circuit (SEQ) and biasing (BIAS) circuit
- Clock output (DIV8)

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Operating Modes

The receiver offers two operating modes selectable by setting the corresponding logic level at pin ENRX.

ENRX	Description			
0	Shutdown mode			
1	Receive mode			

Note: ENRX is pulled down internally.

The receiver's start-up procedure is controlled by a sequencer circuit. It performs the sequential activation of the different building blocks. It also initiates the pre-charging of the data filter and data slicer capacitors in order to reduce the overall start-up time and current consumption during the start-up phase.

At ENRX = 0, the receiver is in shutdown mode and draws only a few nA. The bias system and the reference oscillator are activated after enabling the receiver by a positive edge at pin ENRX. The crystal oscillator (RO) is turned on first. Then the crystal oscillation amplitude builds up from noise. After reaching a certain amplitude level at pin ROI, the whole IC is activated and draws the full receive mode current consumption Icc. This event is used to start the pre-charging of the external data path capacitors. Pre-charging is finished after 5504 clock cycles. After that time the data output pin DTAO output is activated.

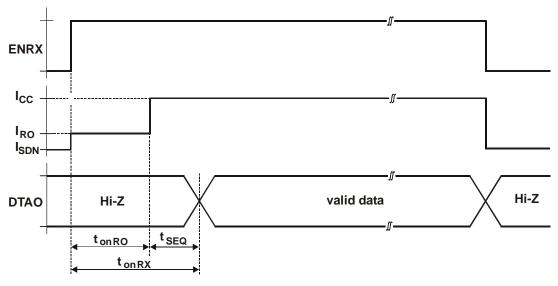


Fig. 2: Timing diagram of start-up and shutdown behavior

1.5 LNA Selection

The receiver features two identical LNAs. Each LNA is a cascode amplifier with a voltage gain of approximately 18dB. The actual gain depends on the antenna matching network at the inputs and the LC tank network between the LNA outputs and mixer input. LNA operation can be controlled by the LNASEL pin.

LNASEL	Description		
0	LNA1 active, LNA2 shutdown		
Hi-Z	LNA1 and LNA2 active		
1	LNA1 shutdown, LNA2 active		

Pin LNASEL is internally pulled to VCC/2 during receive mode. Therefore both LNAs are active if LNASEL is left floating (Hi-Z state).

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1.6 Mixer Section

The mixer section consists of two mixers. Both are double-balanced mixers. The second mixer is built as an image rejection mixer. The first mixer's inputs (MIXP and MIXN) are functionally the same. For single-ended drive, the unused input has to be tied to ground via a capacitor. A soft band-pass filter is placed between the mixers.

RFSEL	Description		
0	Input frequency range 300 to 470MHz		
1	Input frequency range 610 to 930MHz		

Pin RFSEL is used to select the required RF band. The LO frequencies and the proper sidebands for image suppression will be set accordingly.

1.7 IF Filter

The MLX71121 comprises an internal IF filter with a -3dB bandwidth (B3dB) of 300kHz and a -40dB attenuation bandwidth (B40dB) of 1.4MHz. This filter contains three capacitively coupled biquad stages that represent resonant tanks at a filter center frequency (f_{cent}) of 1.8MHz

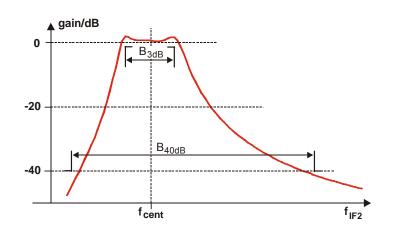


Fig. 3: IF filter tolerance scheme

1.8 IF Amplifier

After having passed the IF filter, the signal is amplified by a high-gain limiting amplifier. It consists of several AC-coupled gain stages with a bandwidth of 400kHz to 11MHz. The overall small-signal pass-band gain is about 80dB. A received-signal-strength indicator (RSSI) signal is generated within the IF amplifier and is available at pin RSSI.

1.9 PLL Synthesizer

The PLL synthesizer consists of a fully integrated voltage-controlled oscillator that runs at 400MHz to 640MHz, a distributed feedback divider chain, an edge-triggered phase-frequency detector, a charge pump, a loop filter and a crystal-based reference oscillator. The PLL is used for generating the LO signals. The LO1 is directly taken from the VCO output, and the LO2 is derived from the LO1 signal passing the N1 counter. Another counter N2 follows N1 to provide the comparison frequency to the PFD. The overall feedback divider ratio N_{tot} is 24. The values of N1 and N2 can be changed via pin RFSEL for selecting the LO1 and LO2 frequencies. The table below shows the range of the LO frequencies.

RFSEL	f _{LO1min} [MHz]	f _{LO1max} [MHz]	f _{LO2min} [MHz]	f _{LO2max} [MHz]	N ₁	N ₂	N _{tot}
0	400	640	100	160	4	6	24
1	400	640	200	320	2	12	24

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Reference Oscillator

A Colpitts crystal oscillator with integrated functional capacitors is used as the reference oscillator (RO) of the PLL synthesizer. The equivalent input capacitance CRO offered to the crystal at pin ROI is about 18pF. The crystal oscillator features an amplitude control loop. This is to assure a very stable frequency over the specified supply voltage and temperature range together with a short start-up time. A buffer amplifier with hysteresis is between RO and PFD. Also a clock divider follows the buffer.

1.10 Clock Output

The clock output pin CKOUT is an open-drain output. For power saving reasons, the circuit is only active if an external pull-up resistor RCL is applied to the pin. Furthermore, RCL can be used to adjust the clock waveform. It forms an RC low-pass together with the capacitive load at the pin, the parasitics of the PCB and the input capacitance of the external circuitry (e.g. a microcontroller).

The clock output feature is disabled if pin CKOUT is connected to ground or left open.

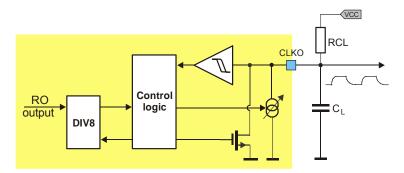


Fig. 4: Clock output implementation

1.11 FSK Demodulator

The integrated FSK demodulator is based on a phase-coincidence demodulator principle. An injection-locked oscillator (ILO) is used as a frequency-dependent phase shifter. This topology features a good linearity of the frequency-phase relationship over the entire locking range. The type of demodulator has no built-in constraints regarding the modulation index. It also offers a wide carrier acceptance range.

In addition, the demodulator provides an AFC loop for correcting the remaining free-running frequency error and drift effects, and also to remove possible frequency offsets between transmitter and receiver frequencies. The AFC loop features a dead band which means that the AFC loop is only closed if the demodulator output voltage leaves the linear region of the demodulator. Most of the time, the control loop is open. This leads to several advantages. The AFC loop bandwidth can be high and therefore the reaction time is short. Furthermore the demodulator itself has no low-end cut-off frequency.

The FSK demodulator has a negative control slope, this means the output voltage decreases by increasing the IF2 frequency. This guarantees an overall positive slope because the mixer section converts the receive frequency to IF2 either with high-low or low-high side injection.

The FSK demodulator is turned off during ASK demodulation.

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1.12 Baseband Data Path

The baseband data path can be divided into a data filter section and a data slicer section.

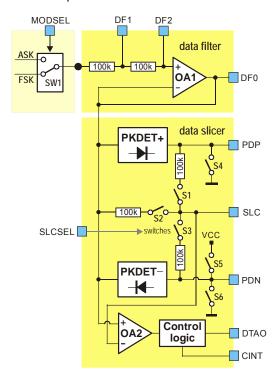


Fig. 5: Block diagram of the data path

The data filter input is either connected to the ASK or to the FSK demodulation output. Pin MODSEL can be used to set the internal switch SW1 accordingly.

MODSEL	Description		
0	ASK demodulation		
1	FSK demodulation		

For ASK demodulation, the RSSI signal of the IFA is used. During FSK demodulation, SW1 is connected to the FSK demodulator output.

The SLCSEL pin is used to control the internal switches depending on operating and slicer mode.

Pins DF1, DF2, DFO, SLC and DTAO are left floating during shutdown mode. So they are in a high-Z state.

1.13 Data Filter

The data filter is formed by the operational amplifier OA1, two internal $100k\Omega$ resistors and two external capacitors. It is implemented as a 2^{nd} order Sallen-Key filter. The low pass filter characteristic rejects noise at higher frequencies and therefore leads to an increased sensitivity.

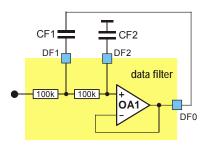


Fig. 6: Data filter

The filter's pole locations can be set by the external capacitors CF1 and CF2. The cut-off frequency f_c has to be adjusted according to the transmission data rate R. It should be set to approximately 1.5 times the fastest expected data rate. For a Butterworth filter characteristic, the data filter capacitors can be calculated as follows.

$$CF1 = \frac{1}{\sqrt{2} \cdot \pi \cdot 100k \cdot f_c}$$

$$CF2 = \frac{CF1}{2}$$

R _{RZ} [kbit/s]	R _{NRZ} [kbit/s]	fc [kHz]	CF1 [pF]	CF2 [pF]
0.6	1.2	0.9	2200	1000
1.2	2.4	1.8	1200	680
1.6	3.2	2.4	1000	470
2.4	4.8	3.6	680	330
3.3	6.6	5	470	220
4.8	9.6	7.2	330	150
6.0	12	9	220	100

1.14 Data Slicer

The purpose of the data slicer is to convert the filtered data signal into a digital output. It can therefore be considered as an analog-to-digital converter. This is done by using the operational amplifier OA2 as a comparator that compares the data filter output with a threshold voltage. The threshold voltage can be derived in two different ways from the data signal.

SLCSEL	Description			
0	Averaging detection mode			
1	Peak detection mode			

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1.14.1 Averaging Detection Mode

The simplest configuration is the averaging or RC integration method. Here an on-chip $100 \mathrm{k}\Omega$ resistor together with an external slicer capacitor (CSL) are forming an RC low-pass filter. This way the threshold voltage automatically adjusts to the mean or average value of the analog input voltage.

To create a stable threshold voltage, the cut-off frequency of the low pass has to be lower than the lowest signal frequency.

$$CSL \ge \frac{\tau_{AVG}}{100k} \qquad \qquad \tau_{AVG} = \frac{1.5}{R_{RZ}}$$

A long string of zeros or ones, like in NRZ codes, can cause a drift of the threshold. That's why a Manchester or other DC-free coding scheme works best.

The peak detectors are disabled during averaging detection mode, and the output pins PDP and PDN are pulled to ground (S4, S6 are closed).

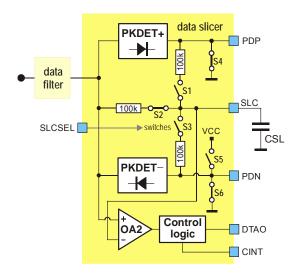


Fig. 7: Data path in averaging detection mode

1.14.2 Peak Detection Mode

Peak detection mode has a general advantage over averaging detection mode because of the part attack and slow release times. Peak detection should be used for all non DC-free codes like NRZ. In this configuration the threshold is generated by using the positive and negative peak detectors. The slicer comparator threshold is set to the midpoint between the high output and the low output of the data filter by an on-chip resistance divider. Two external capacitors (CP1, CP2) determine the release times for the positive and negative envelope. The two on-chip resistors provide a path for the capacitors to discharge. This allows the peak detectors to dynamically follow peak changes of the data filter output voltage. The attack times are very short due to the high peak detector load currents of about 500uA.

The decay time constant mainly depends on the longest time period without bit polarity change. This corresponds to the maximum number of consecutive bits with the same polarity (N_{MAX}).

$$CP1/2 \geq \frac{\tau_{DECAY}}{100k} \qquad \qquad \tau_{DECAY} = \frac{N_{MAX}}{R_{NRZ}}$$

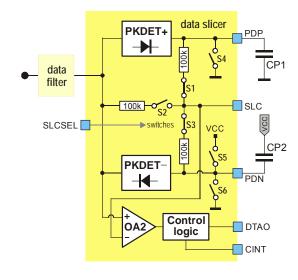


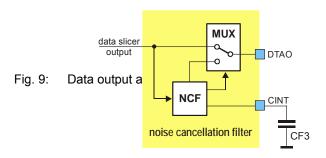
Fig. 8: Data path in peak detection mode

If the receiver is in shutdown mode and peak detection mode is selected then the peak detectors are disabled and the output of the positive peak detector (PDP) is connected to VEE (S4 is closed) and the output of the negative peak detector (PDN) is connected to VCC (S5 is closed). This guarantees the correct biasing of CP1 and CP2 during start-up.

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1.15 Noise Cancellation Filter and Data Output

The data output pin DTAO delivers the demodulated data signal which can be further processed by a noise cancellation filter (NCF). The NCF can be disabled if pin CINT is connected to ground. In this case the multiplexer (MUX) connects the receiver output DTAO directly to the data slicer output.



The noise cancellation filter can suppress random pulses in the data output which are shorter than t_{min}.

CF3 =
$$15 \cdot 10^{-6} \cdot t_{\min} = \frac{15 \cdot 10^{-6}}{R_{NRZ}} = \frac{7.5 \cdot 10^{-6}}{R_{RZ}}$$

The NCF can also operate as a muting circuit. So if the RF input signal is below sensitivity level (or if no RF signal is applied) then the data output will go to a constant DC level (either HIGH or LOW). This can be achieved by setting the bandwidth of the preceding data filter (sec 1.13) about 10 times higher than the bandwidth of the NCF.

Having the NCF activated is a good means for reducing the computing power of the microcontroller that follows the receiver IC for further data processing.

In contrast to a conventional muting (or squelch) circuit, this topology does not need the RSSI signal for level indication. The filtering process is done by means of an analogue integrator. The cut-off frequency of the NCF is set by the external capacitor connected to pin CINT. This capacitor C_{F3} should be set according to the maximum data rate. Below table provides some recommendations..

During receiver start-up a sequencer checks if pin CINT is connected to a capacitor or to ground. The maximum value of C_{F3} should not exceed 12nF. This defines the lowest data rate that can be processed if the noise cancellation filter is activated.

R _{RZ} [kbit/s]	R _{NRZ} [kbit/s]	C _{F3} [nF]
0.6	1.2	12
1.2	2.4	6.8
1.6	3.2	4.7
2.4	4.8	3.3
3.3	6.6	2.2
4.8	9.6	1.5
6.0	12	1.2

In shutdown mode pin DTAO is set to Hi-Z state.

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2 Functional Description

2.1 Frequency Planning

Because of the double conversion architecture that employs two mixers and two IF signals, there are four different combinations for injecting the LO1 and LO2 signals:

LO1 high side and LO2 high side: receiving at f_{RF}(high-high)
 LO1 high side and LO2 low side: receiving at f_{RF}(high-low)
 LO1 low side and LO2 high side: receiving at f_{RF}(low-high)
 LO1 low side and LO2 low side: receiving at f_{RF}(low-low)

As a result, four different radio frequencies (RFs) could yield one and the same second IF (IF2). Fig. 10 shows this for the case of receiving at f_{RF} (high-high). In the example of Fig. 10, the image signals at f_{RF} (low-high) and f_{RF} (low-low) are suppressed by the bandpass characteristic provided by the RF front-end. The bandpass shape can be achieved either with a SAW filter (featuring just a couple of MHz bandwidth), or by the tank circuits at the LNA input and output (this typically yields 30 to 60MHz bandwidth). In any case, the high value of the first IF (IF1) helps to suppress the image signals at f_{RF} (low-high) and f_{RF} (low-low).

The two remaining signals at IF1 resulting from $f_{RF}(high-high)$ and $f_{RF}(high-low)$ are entering the second mixer MIX2. This mixer features image rejection with so-called single-sideband (SSB) selection. This means either the upper or lower sideband of IF1 can be selected. In the example of Fig. 10, LO2 high-side injection has been chosen to select the IF2 signal resulting from $f_{RF}(high-high)$.

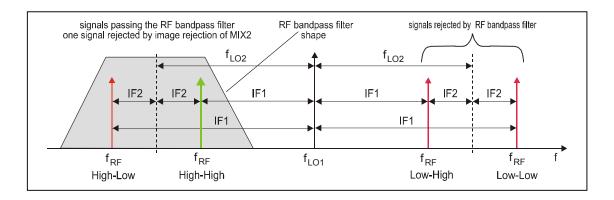


Fig. 10: The four receiving frequencies in a double conversion superhet receiver

It can be seen from the block diagram of Fig. 1 that there is a fixed relationship between the LO signal frequencies (f_{LO1} , f_{LO2}) and the reference oscillator frequency f_{RO} .

$$\mathbf{f}_{\text{LO1}} = \mathbf{N}_1 \cdot \mathbf{f}_{\text{LO2}} \qquad \qquad \mathbf{f}_{\text{LO2}} = \mathbf{N}_2 \cdot \mathbf{f}_{\text{RO}}$$

The operating frequency of the internal IF filter (IFF) and FSK demodulator (FSK DEMOD) are 1.8MHz. Therefore the second IF (IF2) is set to 1.8MHz as well.

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2.2 Calculation of Frequency Settings

The receiver has two predefined receive frequency plans which can be selected by the RFSEL control pin. Depending on the logic level of RFSEL pin the sideband selection of the second mixer and the counter settings for N_1 and N_2 are changed accordingly.

RFSEL	Injection	f _{RFmin} [MHz]	f _{RFmax} [MHz]	N ₁	N ₂
0	high-low	300	470	4	6
1	low-high	610	930	2	12

The following table shows the relationships of several internal receiver frequencies for the two input frequency ranges.

f _{RF} [MHz]	f _{IF1}	f _{LO1}	f _{LO2}	f _{RO}
300 to 470	$\frac{\mathbf{f}_{RF} + \mathbf{N}_1 \mathbf{f}_{IF2}}{\mathbf{N}_1 - 1}$	$\frac{N_{1}(f_{RF} + f_{IF2})}{N_{1} - 1}$	$\frac{f_{RF} + f_{IF2}}{N_1 - 1}$	$\frac{f_{RF} + f_{IF2}}{N_2(N_1 - 1)}$
610 to 930	$\frac{\mathbf{f}_{RF} - \mathbf{N}_1 \mathbf{f}_{IF2}}{\mathbf{N}_1 + 1}$	$\frac{N_{1}(f_{RF} + f_{IF2})}{N_{1} + 1}$	$\frac{f_{RF} + f_{IF2}}{N_1 + 1}$	$\frac{f_{RF} + f_{IF2}}{N_2(N_1 + 1)}$

Given IF2 = 1.8MHz and the corresponding N_1 , N_2 counter settings, above equations can be transferred into the following table.

f _{RF} [MHz]	f _{IF1}	f _{LO1}	f _{LO2}	f _{RO}
300 to 470	$f_{RF} + 7.2MHz$	$4(f_{RF} + 1.8MHz)$		$f_{RF} + 1.8MHz$
	3	3	$f_{RF} + 1.8MHz$	18
610 to 930	$f_{RF} - 3.6MHz$	$2(f_{RF} + 1.8MHz)$	3	$f_{RF} + 1.8MHz$
	3	3		36

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2.3 Standard Frequency Plans

IF2 = 1.8MHz

RFSEL	f _{RF} [MHz]	f _{IF1} [MHz]	f _{LO1} [MHz]	f _{LO2} [MHz]	f _{RO} [MHz]
0	315	107.40	422.40	105.60	17.600000
	433.92	147.04	580.96	145.24	24.206667
1	868.3	288.23	580.07	290.03	24.169444
	915	303.80	611.20	305.60	25.466667

2.4 433/868MHz Frequency Diversity

The receiver's multi-band functionality can be used to operate at two different frequency bands just by changing the logic level at pin RFSEL and without changing the crystal. This feature is applicable for common use of the 433 and 868MHz bands. Below table shows the corresponding frequency plans.

IF2 = 1.8MHz

RFSEL	f _{RF} [MHz]	f _{IF1} [MHz]	f _{LO1} [MHz]	f _{LO2} [MHz]	f _{RO} [MHz]
0	433.25	146.82	580.07	145.02	24.169444
1	868.3	288.23	580.07	290.03	24.109444

300 to 930MHz FSK/FM/ASK Receiver

3 Pin Definitions and Descriptions

Pin No.	Name	I/O Type	Functional Schematic	Description
3	LNAO1	analog output	Vbias LNAO1	LNA output 1
1	LNAI1	analog input	LNAI1 VEE VEE	LNA input 1
2	VEE	ground		negative supply voltage
4	MIXP	analog input	VCC Vbias VCC MIXN	MIX1 positive input
5	MIXN	analog input	4 VEE VEE TO SEE	MIX1 negative input
6	LNAO2	analog output	Vbias LNAO2 Vbias CNAO2 Vbias Vbias VEE	LNA output 2
8	LNAI2	analog input	LNAI2 VEE VEE	LNA input 2
7	VEE	ground		negative supply voltage
9	VCC	supply		positive supply voltage
10	MIXO	analog output	not used pin left open	mixer 2 output
11	VEE	ground		negative supply voltage
12	IFAP	analog input	not used	IF amplifier positive input
13	IFAN	analog input	pins left open	IF amplifier negative input
14	MODSEL	CMOS input	MODSEL 400 VCC WCC WCC WCC WCC WCC WCC WCC WCC WCC	modulation select input

Pin No.	Name	I/O Type	Functional Schematic	Description
15	SLCSEL	CMOS input	SLCSEL VCC VCC VCC VCC VCC VCC VCC VCC VCC VC	slicer mode select input
16	DF2	analog I/O	DF2 400 VCC P	data filter connection 2
17	DF1	analog I/O	VEE VCC VCC VCC VCC VCC VCC VCC VCC VCC	data filter connection 1
18	DFO	analog output	DFO 400 VEE	data filter output
19	SLC	analog input	SLC 400 100k 100k 100k	slicer reference input
20	PDP	analog output	PDP 400 VEE	peak detector positive output
21	PDN	analog output	PDN 400 VEE	peak detector negative output

Pin No.	Name	I/O Type	Functional Schematic	Description
22	VCC	supply		positive supply voltage
23	CINT	analog input	CINT VCC VCC VEE	capacitor for noise cancella- tion filter pin must be connected to ground if noise cancellation filter is not used
24	RSSI	analog output	RSSI 400 VEE VEE	receive signal strength indication
25	ROI	analog input	VCC PVCC PVCC PVCC PVCC PVCC PVCC PVCC	reference oscillator input
26	TEST	CMOS input	not used connect to ground	test pin
27	IFSEL	CMOS input	not used connect pin to ground	IF select input
28	CLKO	CMOS output	CLKO CLKO VEE	clock output connect pull-up resistor to activate clock
29	DTAO	CMOS output	DTAO VCC DVCC	data output
30	ENRX	CMOS input	ENRX 400 VCC VCC VCC VCC VCC VCC VCC VCC VCC V	enable RX mode control



Pin No.	Name	I/O Type	Functional Schematic	Description
31	RFSEL	CMOS input	RFSEL 400 VCC VCC VCC VCC VCC VCC VCC VCC VCC V	receive frequency select input
32	LNASEL	CMOS input	LNASEL 400 32 VEE	LNA select input

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4 Technical Data

4.1 Absolute Maximum Ratings

Operation beyond absolute maximum ratings may cause permanent damage of the device.

Parameter	Symbol	Condition	Min	Max	Unit
Supply voltage	V_{CC}		0	7	V
Input voltage	V_{IN}		-0.3	V _{CC} +0.3	V
Storage temperature	T_{STG}		-55	150	°C
Junction temperature	TJ			150	°C
Thermal Resistance	R _{thJA}			22	K/W
Power dissipation	P _{diss}			0.12	W
Electrostatic discharge	V _{ESD}	HBM according to MIL STD 833D, method 3015.7	±1		kV

4.2 Normal Operating Conditions

Parameter	Symbol	Condition	Min	Max	Unit	
Supply voltage	V_{CC}		2.1	5.5	V	
Operating temperature	T _A		-10	70	°C	
Input low voltage (CMOS)	V _{IL}	ENRX, SEL pins		0.3*V _{CC}	V	
Input high voltage (CMOS)	V _{IH}	ENRX, SEL pins	0.7*V _{CC}		V	
Input frequency range	f_{RF}	RFSEL=0	300	470	MHz	
Input frequency range	'RF	RFSEL=1	610	930	IVII IZ	
First IF range	f	RFSEL=0	100	170	MHz	
Thistin range	f _{IF1}	RFSEL=1	200	310	IVIITZ	
LO1 range (VCO frequency)	f _{LO1}	$f_{LO1} = 24*f_{REF}$	400	640	MHz	
LO2 range	f _{LO2}	RFSEL=0, f _{LO2} = f _{LO1} / 4	100	160	MHz	
LOZ range		RFSEL=1, $f_{LO2} = f_{LO1} / 2$	200	320		
XOSC frequency	f_{REF}	set by the crystal	16	27	MHz	
CLKO frequency	f _{CLK}	$f_{CLK} = f_{REF} / 8$	2.0	3.375	MHz	
FSK deviation	Δf		±10	±100	kHz	
Data rata ASK	D	bi-phase code		50		
Data rate ASK	R _{ASK}	NRZ		100	l de m e	
Data rate FSK	D	bi-phase code		50	kbps	
Data rate FSK	R _{FSK}	NRZ		100		

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4.3 DC Characteristics

all parameters under normal operating conditions, unless otherwise stated; typical values at T_A = 23 °C and V_{CC} = 3 V, all parameters based on test circuits as shown Fig. 11

Parameter	Symbol	Condition	Min	Тур	Max	Unit			
Operating Currents	Operating Currents								
Shutdown current	I _{SDN}	ENRX=0, T _A = 70°C		50	150	nA			
Supply current reference oscillator	I _{RO}	ENRX=1, t < t _{onRO}		1.5		mA			
Supply current, FSK	I _{FSK}	ENRX=1, MODSEL=1 SLCSEL=0 LNASEL=0 or 1		10.2		mA			
Supply current, ASK	I _{ASK}	ENRX= 1, MODSEL= 0 SLCSEL=0 LNASEL=0 or 1		9.8		mA			
Digital Pin Characteristics (exc	cept of LN	ASEL)							
Input low voltage (CMOS)	V _{IL}	ENRX, SEL pins			0.3*V _{CC}	V			
Input high voltage (CMOS)	V _{IH}	ENRX, SEL pins	0.7*V _{CC}			V			
Pull down current ENRX pin	I _{PDEN}	ENRX=1	2	8	30	μA			
Low level input current ENRX pin	I _{INLEN}	ENRX=0			1	μA			
High level input current	I _{INHSEL}	SEL pins			1	μA			
Low level input current	I _{INLSEL}	SEL pins			1	μA			
LNASEL Pin Characteristics									
Input voltage LNA1 active	V _{LNASEL1}	ENRX=1			0.1*V _{CC}	V			
Input voltage LNA2 active	V _{LNASEL2}	ENRX=1	0.9*V _{CC}			V			
DTAO Pin Characteristics									
Output low voltage	V _{OL}	DTAO pin, $I_{SINK} = 600 \mu A$			0.3*V _{CC}	V			
Output high voltage	V _{OH}	DTAO pin, I _{SOURCE} = 600µA	0.7*V _{CC}			V			

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4.4 AC System Characteristics

all parameters under normal operating conditions, unless otherwise stated; typical values at T_A = 23 °C and V_{CC} = 3 V, all parameters based on test circuits as shown Fig. 11

Parameter		Symbol	Condition		Min	Тур	Max	Unit
Receive Characteristics								
Input Sensitivity 1)	MODSEL	RFSEL						
	315MHz	P _{min1}		0		-107		dBm
FSK	433MHz	P _{min2}	1			-107		
FSK	868MHz	P _{min3}		1		-104		
	915MHz	P _{min4}		ļ		-102		
	315MHz	P _{min5}		0		-112		
ASK	433MHz	P _{min6}	0	U		-112		dBm
ASK	868MHz	P _{min7}		1		-108		asm
	915MHz	P _{min8}		'		-105		
Maximum input sign	al – FSK	P _{max, FSK}	MODSEL=1	MODSEL=1		-10		dBm
Maximum input sign	al – ASK	$P_{\text{max, ASK}}$	MODSEL=0, M>70dB			-10		dBm
Spurious emission		P _{spur}					-54	dBm
Image rejection 1 st IF		IR ₁	w/o SAW filt	ter		20		dB
Image rejection 2 nd IF		IR ₂				25		dB
LNA Parameters								
Voltage gain		G _{LNA}	depends or LC tank	n external		18		dB
IF Filter Parameter	s							
Center frequency		f_{cent}				1.8		MHz
3dB bandwidth		B _{3dB}				300		kHz
40dB bandwidth		B _{40dB}				1.4		MHz
IF Amplifier / RSSI				·				
Operating frequency		f _{IFA}			0.4		11	MHz
RSSI usable range		DR _{RSSI}	continuous range		45		55	dB
RSSI slope		S _{RSSI}				20		mV/dB
FSK Demodulator								
Input frequency range		f _{DEM}				1.8		MHz
Carrier acceptance range		Δf_{DEM}				±80		kHz
Demodulator sensitivity		S _{DEM}				5		mV/ kHz

¹⁾ at 4kbps NRZ, BER ≤ 3·10⁻³, peak detector data slicer, LNASEL = 0 or 1

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Parameter	Symbol	Condition	Min	Тур	Max	Unit				
Baseband Data Path										
Data filter bandwidth	B_{DF}	depending on CF1, CF2			100	kHz				
Peak detector load current	I _{PKD}			500		μA				
Start-up Parameters										
Reference oscillator start-up time	t _{onRO}	depending on crystal parameters		350	650	μs				
Sequencer time	t _{SEQ}	5504 / f _{REF}	200	250	350	μs				
Receiver start-up time	$t_{\sf onRX}$	t _{onRO} + t _{SEQ}		0.6	1	ms				
Frequency Stability										
Frequency pulling by supply voltage	df _{VCC}				±3	ppm/V				

4.5 External Components

Parameter	Symbol	Condition	Min	Max	Unit					
Crystal Parameters										
Crystal frequency	f_0	fundamental mode, AT	16	27	MHz					
Load capacitance	C _L		10	15	pF					
Static capacitance	C_0			5	pF					
Series resistance	R ₁			60	Ω					
Noise Cancellation Filter										
Integrator capacitor	CF3	depends on data rate		12	nF					
Clock Output										
Pull-up resistor	RCL		600		Ω					
Load capacitance	C _L			50	pF					



5 Test Circuit

5.1 Antenna Diversity Application Circuit

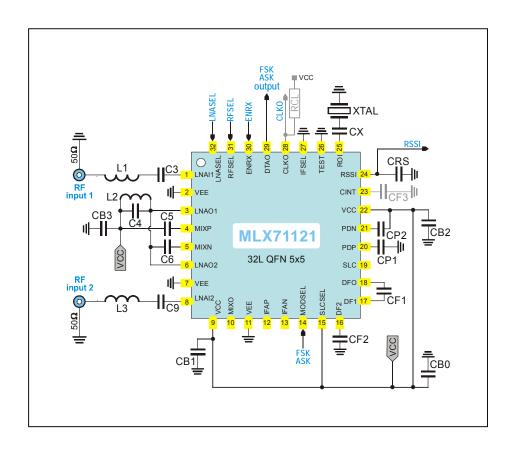


Fig. 11: Antenna diversity circuit schematic, peak detectors activated

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5.1.1 Test Circuit Component List of Figures 11

Part	Size	Value @ 315 MHz	Value @ 433.92 MHz	Value @ Value @ 915 MHz		Tol.	Description		
C3	0603	100 pF	100 pF	100 pF 100 pF		±5%	LNA input filtering capacitor		
C4	0603	4.7 pF	3.9 pF	2.2 pF	1.5 pF	±5%	LNA output tank capacitor		
C5	0603	100 pF	100 pF	100 pF	100 pF	±5%	MIX1 positive input matching capacitor		
C6	0603	100 pF	100 pF	100 pF	100 pF	±5%	MIX1 negative input matching capacitor		
C9	0603	100 pF	100 pF	100 pF	100 pF	±5%	LNA input filtering capacitor		
CB0	0805	33 nF	33 nF	33 nF	33 nF	±10%	decoupling capacitor		
CB1	0603	330 pF	330 pF	330 pF	330 pF	±10%	decoupling capacitor		
CB2	0603	330 pF	330 pF	330 pF	330 pF	±10%	decoupling capacitor		
CB3	0603	330 pF	330 pF	330 pF	330 pF	±10%	decoupling capacitor		
CF1	0603	680 pF	680 pF	680 pF	680 pF	±10%	data low-pass filter capacitor, for data rate of 4 kbps NRZ		
CF2	0603	330 pF	330 pF	330 pF	330 pF	±10%	data low-pass filter capacitor, for data rate of 4 kbps NRZ		
CF3	CF3 0603 value according to the data rate						optional capacitor for noise cancellation		
01 0	connected to ground if noise filter not used		ısed	±10%	filter				
CP1	0603	33 nF	33 nF	33 nF 33 nF		±10%	positive PKDET capacitor, for data rate of 4 kbps NRZ		
CP2	0603	33 nF	33 nF	33 nF	33 nF	±10%	negative PKDET capacitor, for data rate of 4 kbps NRZ		
CRS	0603	1 nF	1 nF	1 nF	1 nF	±10%	RSSI output low pass capacitor		
CSL	0603	100 nF	100 nF	100 nF	100 nF	±10%	data slicer capacitor,		
COL	0003		for averaging dete	ection mode only		±1076	for data rate of 4 kbps NRZ		
CX	0603	27 pF	27 pF	27 pF	27 pF	±5%	crystal series capacitor		
L1	0603	56 nH	27 nH	0 Ω	0 Ω	±5%	matching inductor		
L2	0603	27 nH	15 nH	3.9 nH	3.9 nH	±5%	LNA output tank inductor		
L3	0603	56 nH	27 nH	0 Ω	0 Ω	±5%	matching inductor		
RCL	0603	3.3 kΩ	3.3 kΩ	3.3 kΩ	3.3 kΩ	±5%	optional CLK output resistor, to clock output signal generated		
XTAL	SMD				25.46667 MHz		fundamental-mode crystal from Telcona,		
	5x3.2	±20ppm cal., ±30ppm temp.					or equivalent part		

Note: NIP – not in place, may be used optionally



6 Package Description



The device MLX71121 is RoHS compliant.

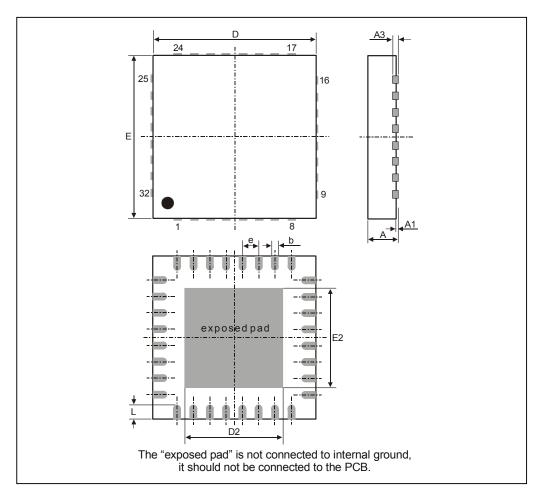


Fig 12: 32L QFN 5x5 Quad

all Dimension in mm											
	D	Е	D2	E2	Α	A1	А3	L	е	b	
min	4.75	4.75	3.00	3.00	0.80	0	0.20	0.3	0.50	0.18	
max	5.25	5.25	3.25	3.25	1.00	0.05		0.5		0.30	
all Dime	all Dimension in inch										
min	0.187	0.187	0.118	0.118	0.0315	0	0.0079	0.0118	0.0197	0.0071	
max	0.207	0.207	0.128	0.128	0.0393	0.002		0.0197		0.0118	

6.1 Soldering Information

 The device MLX71121 is qualified for MSL3 with soldering peak temperature 260 deg C according to JEDEC J-STD-20.

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7 Reliability Information

This Melexis device is classified and qualified regarding soldering technology, solderability and moisture sensitivity level, as defined in this specification, according to following test methods:

Reflow Soldering SMD's (Surface Mount Devices)

IPC/JEDEC J-STD-020

"Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices (classification reflow profiles according to table 5-2)"

Wave Soldering SMD's (Surface Mount Devices)

EN60749-20

"Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat"

Solderability SMD's (Surface Mount Devices)

EIA/JEDEC JESD22-B102

"Solderability"

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

8 ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.



MLX71121 300 to 930MHz FSK/FM/ASK Receiver

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